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U-SILICON SEMICONDUCTOR AND HIGH-K GA
DIELECTRIC METAL OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS

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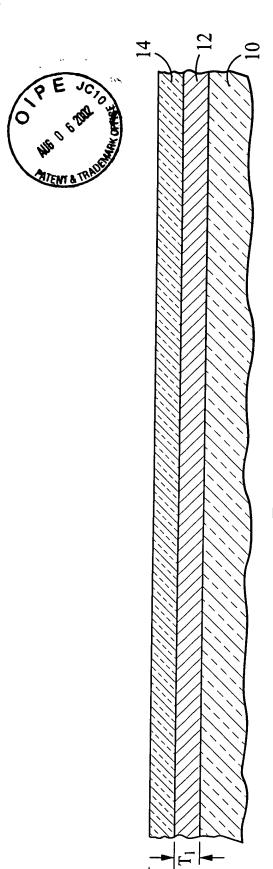


FIG. 1

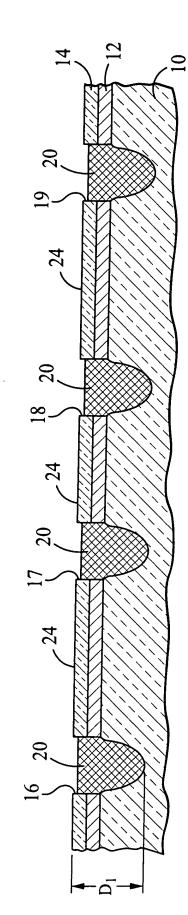
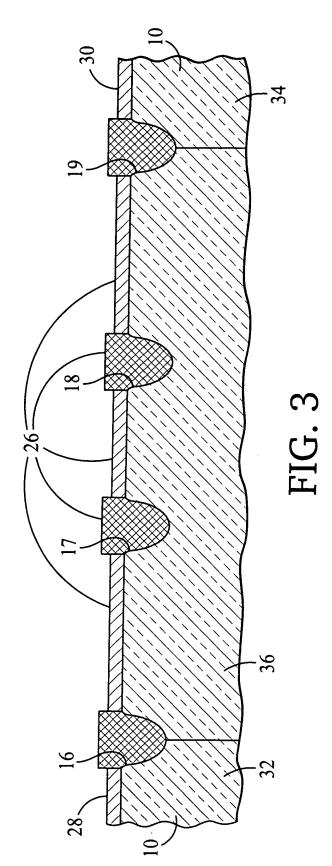


FIG. 2





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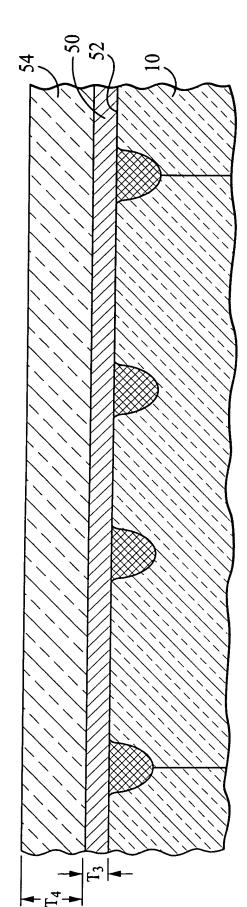
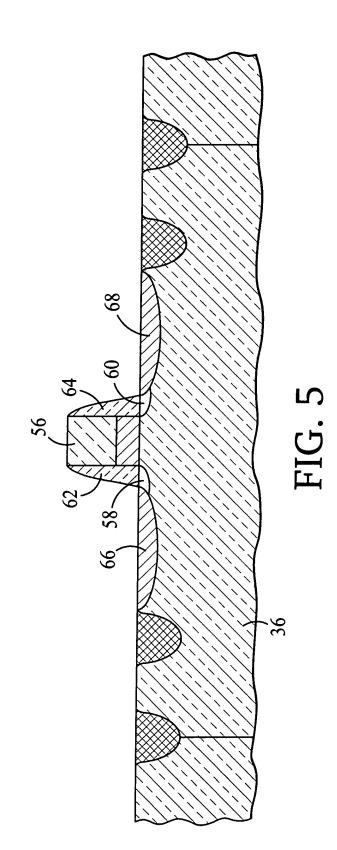


FIG. 4

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